Q1. In the absence of an external electric field on a di-polar substance, the electric dipoles are: (A) parallel

(B)alternatively anti-parallel (C) randomly oriented

(D) none

Q2. Which Maxwell's equation can be used to derive equation of continuity?

a) Maxwell's 1st equation

b) Maxwell's 2nd equation

c) Maxwell's 3rd equation

d) Maxwell's 4th equation

Q3. The value of permittivity of free space is

 $(a)8.85 \times 10^{-12} \text{ F/m}$

(b) 8.85×10^{-12} C/m

(c) 8.85×10^{-12} J/m

(d) 8.85×10^{-12} KJ/m

Q4. Maxwell's third equation is related to

(a) Gauss law for electricity

(b) Gauss law for magnetism

(c) Ampere's law

(d) Faraday's law of induction

Q5. Which of the following relation is true for Poisson's equation?

(a)
$$\nabla^2 V = \frac{\rho}{\epsilon_0}$$

(b)
$$\nabla^2 V = -\frac{\rho}{\epsilon_0}$$

(c)
$$\nabla^2 V = \frac{q}{\epsilon_0}$$

(d)
$$\nabla^2 V = -\frac{q}{\epsilon_0}$$

- **Q6.** Which statement correctly defines the gauss divergence theorem
- a. line integral of the field is equal to volume integral of that field
- b. surface integral of a field is equal to the volume integral of divergence of that field
- c. volume integral is equal to the surface integral of divergence of that field
- d. None of above
- Q7. How much Work will be done by 2coulomb charge moving under 20 V?
- a) 100 units

b) 80 units

c) 40 units

d) 10 units

- Q8. The Gaussian surface for a line charge will be
- a) Sphere

b) Cylinder

c) Cube

d) Cuboid

Q9. Which of the following equation signify that magnetic monopole does not exist.

a.
$$\vec{\nabla} \times \vec{B} = \mu \vec{J}$$

b.
$$\overrightarrow{\nabla} \cdot \overrightarrow{B} = 0$$

c.
$$\vec{\nabla} \cdot \vec{B} = \mu \vec{J}$$

Q10. The reason for non existence of magnetic monopoles is a) The magnetic field cannot be split c) Due to magnetization b) Due to permeability d) Due to magnetostriction Q11. The del operator is called as a) Gradient b) Curl c) Divergence d) Vector differential operator Q12. If D is the displacement vector and ρ is the charge density of any closed surface than equation $\nabla \cdot D = \rho$ (a)Maxwell 1st equation (b) Maxwell 2nd equation (c) Maxwell 3rd equation (d) Maxwell 4th equation Q13. Which of the following can be used in vibrational analysis of structure? a) Maser b) Quarts c) Electrical waves d) Laser Q14. In population inversion (a) The number of electrons in ground and higher energy states are same (b) The number of electrons in ground energy sate is more than the higher energy state is more than the higher (c) The number of electrons in the higher energy state is more than the higher energy state

the number of electrons in the higher energy state is larger

than in the lower energy state

(d) None of these

| Q15. Einstein's coefficient (a) A_{21} (c) B_{12} | t of stimulated emission of radiation (b)B ₂₁ (d) None | on is denoted by | - |
|---|---|---|------------------------------------|
| Q16. Hologram is the result of (a) interference of object and reference beam (c) diffraction of the object and reference beam | | (b) polarization of the object and reference (d) both (a) and (b) | |
| Q17. The Einstein Co-effi a. $(8\pi hc^3)/v^3$ | cient relation is b. (8πh v³)/c³ | c. (8πhc)/v ³ | d. (8πhc)/v |
| Q18. Pumping source pres (A) optical pumping (C) chemical pumping | (B) electrical pumping | | |
| Q19. Calculate the wavelethe excited state and ground (A) 2.8 nm | ength of light emitted in spontane nd state. (B) 3472 nm | ous emission with an energ | gy gap of 2.8eV between (D) 443 nm |

| Q19. Calculate the wavelengthe excited state and ground | | | |
|--|--|---|--|
| (A) 2.8 nm | (B) 3472 nm | (C) 554 nm | (D) 443 nm |
| Q20. The ground state and a number of atoms in the exci- meV at room temperature.) (A) $\approx 10^{-30}$ (B) 0.095 (C) $\approx 10^{-31}$ (D) None of the above | the first excited state of Ruby ited state to that in the ground | are separated by 1.8 eV. of state at room temperature | Calculate the ratio of the c. (use value of kT of 25.7 |
| Q21. He-Ne laser produces (A) 1064 nm | a laser beam of wavelength (B) 532 nm | (C) 632.8 nm | (D) 694 nm |
| Q22. The key process behind (a) Spontaneous emission | nd the Lasing action is (b) Stimulated emission | (c) Absorption | (d) None of the above. |

| Q23. The population inversion (a) Metastable state | n process is observed due to the (b) Excited state | existence of (c) Ground state | (d) All of these |
|---|--|---|--------------------|
| Q24. In He-Ne laser the ratio | of He-Ne gas molecules in the | • | (u) An or these |
| (a) 1:10 | (b) 10:1 | (c) 1:1 | d) 1:2 |
| Q25. Optical fibres are used in a) Broadcast television | n b) Transmission | c) Welding | d) Both a and b |
| Q26. The speed of light is a. 186,000 mi/h | b. 300 mi/h | c. 300,000 m/s | d. 300,000,000 m/s |
| Q27. In the structure of fiber, a. reflection | the light is guided through the ob. refraction | core due to total internal _ c. diffraction | d. dispersion |
| Q28. Which laser emits light | in the visible range 400 to 700 n | ım? | |
| a. Argon-ion | b. Nitrogen | c. Carbon-dioxide | d. Neodymium-YAG |
| Q29. The principle used in the (A) Interference (C) Total internal reflection | e propagation of light in optical (B) Diffraction (D) Polarization | fiber is | • |

Q30. In an optical fiber, the propagation angle of the light must be equal to or less than b) Incident angle c) Critical angle d) Refractive angle a) Acceptance angle Q31. In an optical fiber, dispersion means (a) Pulse broadening (b) Pulse distortion (c) Pulse rise time (d) None of these c (32) The normalized frequency also known as (a) Special frequency (b) Resonant frequency (c) Threshold frequency (d)All of these Q33. The bandwidth of optical fibre b) 900 PHz c) 900 THz d) 900 EHz a) 900M Hz Q34. Dispersion in optical fibers occur due to (a) frequency dependent refractive index of fiber (b) scattering of light by the molecules (c) both a and b (d) none of the above

Q35. In an optical fiber, dispersion means

- (a) Pulse broadening
- (b) Pulse excitation
- (c) Pulse rise time
- (d) None of these

Q36. Snell's law is related to

- (a) Light reflection
- (b) Light refraction
- (c) Light absorption
- (d) Light emission

| Q37. Ψ (r,t) is the wave fu | inction associated with movi | ing particle at the particular p | oint in |
|--|--------------------------------|----------------------------------|-------------------|
| space and | t. | | |
| a x,y,z; temperature | b. x,y,z; time | c. x; time | d. x, temperature |
| Q38. The wave function a. does not give any prope b. describes the behavior c. only shows the direction d. None of the above | of single particle or photon | | |
| Q39. The de Broglie hypo a. wave nature of radiation c. wave nature of photons | ns | b. wave nature of ele | • |
| Q40. De Broglie wavelen | gth of an electron accelerated | d by a potential V is | |
| $\mathbf{a)} \sqrt{\frac{150}{\mathbf{v}}} \mathbf{\mathring{A}}$ | | , | |
| b) $\sqrt{\frac{225}{v}}$ Å | | | |
| c) $\sqrt{\frac{275}{v}}$ Å | | | |
| d) $\sqrt{\frac{375}{V}}$ Å | | | |

- a. only as a particle
- c. both as particle and wave

b. only as a wave

d. none of these

Q42. In photoelectric effect, photocurrent depends upon

- A). Frequency of incident light
- C). Both A & B

B). Intensity of incident light

D). None of these

Q43. Which of the following expressions gives the energy E of a photon?

a)
$$E = mc^2/2$$

b)
$$E = mv^2/2$$

c)
$$E = hc$$

d)
$$E = h_{\mathbf{i}}$$

and the same of th

Q44. Wave function Ψ gives the idea for

- a) Probability of finding the particle
- c) Momentum of the particle

b) Energy of the particle

d) Energy and momentum of the particle

Q45. Uncertainty principle is applicable to

- A. macroscopic particles
- C. heavier particles

B. microscopic particles

D. both A and B

Q46. Which one of the following energy value of a particle in infinite potential well of length L is allowed

a.
$$\frac{n^2\pi^2\hbar^2}{2mL}$$

b.
$$\frac{n^2h^2}{2mL^2}$$

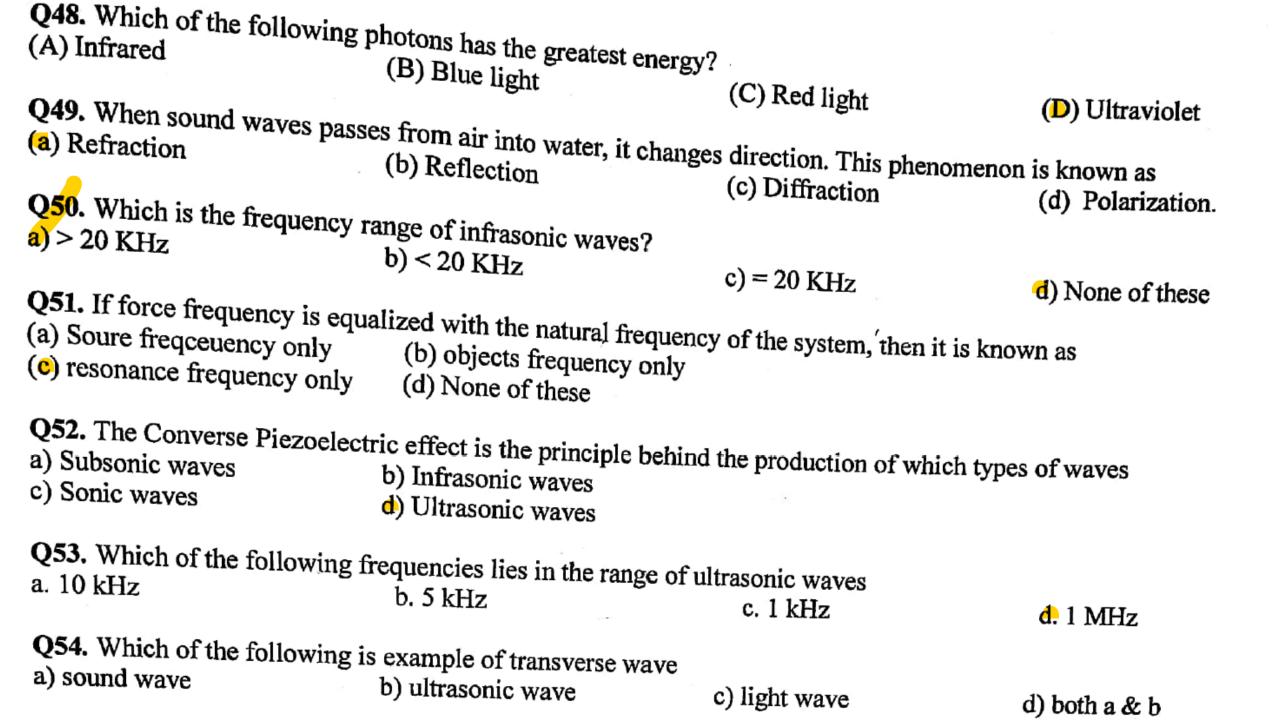
c.
$$\frac{L^2\pi^2h^2}{2mn^2}$$

$$\frac{n^2\pi^2\hbar^2}{2mL^2}$$

Q47. Wave packets comprises a group of waves

A. of same velocity and same wavelength

B. of slightly different velocity and wavelength D. None



| Q55. Superposition of crest at A. Destructive interference. B. Constructive interference. C. Diffraction. D. Polarization. | nce | | | | |
|--|--|---|--|--|--|
| Q56. Infrasonic sound can be a. Human being | heard by b. Bat | c. Rhinoceros | d. Dog | | |
| Q57. For destructive interference, path difference is (a) odd number of half wavelengths (c) whole number of wavelengths | | (b) even number of hall(d) even whole number | (b) even number of half wavelengths(d) even whole number of wavelengths | | |
| Q58. Magnetostriction Effect a. Strength of the magnetic b. Property of the material c. Direction of the magnetic d. None of the above | field | | | | |
| Q59. What will be the wavele | ngth of ultrasonic waves | in air (velocity 330 m/s), if the | frequency of the waves is | | |
| (A) 2.65 cm | (B) 1.65 cm | (C) 0.65 cm | (D) 11.65 cm | | |
| Q60. Which of the following a) Magnetostriction effect | effects can be used to pro b) Doppler Effect | duce ultrasonic waves? c) Magnetic effect | d) Sound effect | | |

Q61. The resistance of a straight conductor does not depend on its

a) temperature b) length
c) material d) shape of cross section

Q62. Flow of electrons is affected by the following:
a) Thermal vibrations b) Impurity atoms c) Crystal defects d) All of these

Q63. Addition of trivalent atom of group III to semiconductor results into

a. N- type semiconductors

b. P-type semiconductors

c. Both (a) and (b)

d. None of these

Q64. Hall coefficient is given by

a) 1/nq

b) -1/nq

c) q/ne

d) 1/q

Q65. For a p-type semiconductor A. Silicon is doped with Silver B. Silicon is doped with Aluminium

- C. Silicon is doped with Antimony
- D. None of these

Q66. Considering that there are 5.2×10^{28} electrons/m³ in copper. What will be the value of Hall coefficient?

- a) $1.2 \times 10^{-10} \text{ m}^3/\text{C}$
- b) $5.2 \times 10^{-10} \text{ C}$
- c) $3.4 \times 10^{-10} \text{ m}^3/\text{C}$
- d) $1.2 \times 10^{-11} \text{ m}^3/\text{C}$

Q67. In intrinsic semiconductors, number of electrons

(A) Equal to number of holes

(B) Greater than number of holes

(C) Less than number of holes

(D) Can not define

Q68. Assertion (A): Germanium is less efficient in the emission of photons.

Reason (R): Germanium is an indirect bandgap semiconductor.

- (a) Both A and R are true and R is the correct reason for A
- (b) Both A and R are true but R is not the correct reason for A
- (c) A is true but R is false
- (d) A is false but R is true

Q69. Recombination takes place when

- (a) an electron falls into a hole
- (b) a positive and a negative ion bond together
- (c) a valence electron becomes a conduction
- (d) a crystal is formed

Q70. In p-type semiconductor _____ are the minority carriers

- (a) electrons
- (b) holes
- (c) photons
- (d) phonon

-- End of Question Paper --